**FORM PTO-1449** 



U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY DOCKET NUMBER **NEW PATENT APPLICATION** 024808-00014

APPLICANT

Kazunari HONMA, et al.

FILING DATE

August 1, 2003

GROUP

(Use several sheets if necessary)

## **U.S. PATENT DOCUMENTS**

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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	AA						
	АВ						
	AC		· .				
	AD						
	AE			<u> </u>			·
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## **FOREIGN PATENT DOCUMENTS**

1.0		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	<u>TR</u> A	NSLAT	ION PART.
/HW/	AG	11-068057	March 9, 1999	Japan			ļ		х
/HW/	АН	2001-072416	March 21, 2001	Japan					х
/HW/	ΑI	11-080181	March 26, 1999	Japan					X
	AJ								
	AK								
	AL				<u> </u>				

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

/HW/	АМ	Item I "Low Temperature Deposition Material" Section 4 "New Deposition Material" Ferroelectric Memory Advanced Process September 13, 1999
	AN	
	AO	

EXAMINER	/Howard Weiss/	DATE CONSIDERED 04/23/2007				
*EXAMINER:	Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in					